# Low-power 2-input EXCLUSIVE-OR gate Rev. 5 — 28 June 2012

**Product data sheet** 

#### **General description** 1.

The 74AUP1G86 provides the single 2-input EXCLUSIVE-OR function.

Schmitt-trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire V<sub>CC</sub> range from 0.8 V to 3.6 V.

This device ensures a very low static and dynamic power consumption across the entire V<sub>CC</sub> range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using I<sub>OFF</sub>.

The I<sub>OFF</sub> circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

#### 2. **Features and benefits**

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
  - ◆ JESD8-12 (0.8 V to 1.3 V)
  - ◆ JESD8-11 (0.9 V to 1.65 V)
  - JESD8-7 (1.2 V to 1.95 V)
  - ◆ JESD8-5 (1.8 V to 2.7 V)
  - ◆ JESD8-B (2.7 V to 3.6 V)
- ESD protection:
  - HBM JESD22-A114F Class 3A exceeds 5000 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; I<sub>CC</sub> = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V<sub>CC</sub>
- I<sub>OFF</sub> circuitry provides partial power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



## 3. Ordering information

Table 1. Ordering information

Type number	Package							
	Temperature range	Name	Description	Version				
74AUP1G86GW	–40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1				
74AUP1G86GM	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 $\times$ 1.45 $\times$ 0.5 mm	SOT886				
74AUP1G86GF	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 $\times$ 1 $\times$ 0.5 mm	SOT891				
74AUP1G86GN	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $0.9 \times 1.0 \times 0.35$ mm	SOT1115				
74AUP1G86GS	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 $\times$ 1.0 $\times$ 0.35 mm	SOT1202				
74AUP1G86GX	–40 °C to +125 °C	X2SON5	X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body $0.8 \times 0.8 \times 0.35$ mm	SOT1226				

## 4. Marking

#### Table 2. Marking

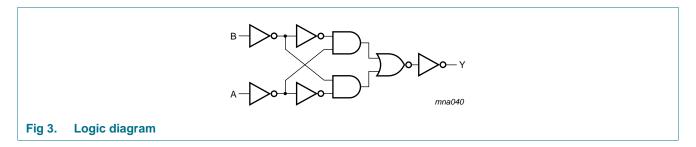
Type number	Marking code <sup>[1]</sup>
74AUP1G86GW	рН
74AUP1G86GM	рН
74AUP1G86GF	рН
74AUP1G86GN	рН
74AUP1G86GS	рН
74AUP1G86GX	рН

<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

## 5. Functional diagram

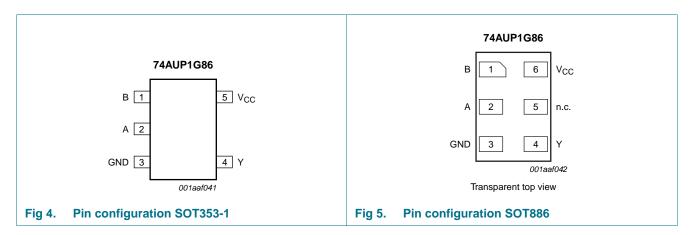


#### Low-power 2-input EXCLUSIVE-OR gate



## 6. Pinning information

## 6.1 Pinning





Low-power 2-input EXCLUSIVE-OR gate

## 6.2 Pin description

Table 3. Pin description

Symbol	Pin		Description			
	TSSOP5 and X2SON5 XSON6					
В	1	1	data input			
A	2	2	data input			
GND	3	3	ground (0 V)			
Υ	4	4	data output			
n.c.	-	5	not connected			
V <sub>CC</sub>	5	6	supply voltage			

## 7. Functional description

Table 4. Function table[1]

Input		Output
Α	В	Υ
L	L	L
L	Н	Н
Н	L	Н
Н	Н	L

<sup>[1]</sup> H = HIGH voltage level; L = LOW voltage level.

## 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+4.6	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V	-50	-	mA
$V_{I}$	input voltage		<u>[1]</u> –0.5	+4.6	V
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode	<u>[1]</u> –0.5	+4.6	V
I <sub>O</sub>	output current	$V_O = 0 V \text{ to } V_{CC}$	-	±20	mA
I <sub>CC</sub>	supply current		-	+50	mA
$I_{GND}$	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$	[2] -	250	mW

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>[2]</sup> For TSSOP5 packages: above 87.5  $^{\circ}$ C the value of P<sub>tot</sub> derates linearly with 4.0 mW/K. For XSON6 and X2SON5 packages: above 118  $^{\circ}$ C the value of P<sub>tot</sub> derates linearly with 7.8 mW/K.

## 9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		0.8	3.6	V
$V_{I}$	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	$V_{CC}$	V
		Power-down mode; V <sub>CC</sub> = 0 V	0	3.6	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	$V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	0	200	ns/V

## 10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 25	5 ℃					
$V_{IH}$	HIGH-level input voltage	V <sub>CC</sub> = 0.8 V	$0.70 \times V_{CC}$	-	-	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	$0.65 \times V_{CC}$	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
$V_{IL}$	LOW-level input voltage	V <sub>CC</sub> = 0.8 V	-	-	$0.30 \times V_{CC}$	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	$0.35 \times V_{CC}$	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_{O} = -20 \mu A$ ; $V_{CC} = 0.8 \text{ V}$ to 3.6 V	$V_{CC}-0.1$	-	-	V
		$I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.75 \times V_{CC}$	-	-	V
		$I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	1.11	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.32	-	-	٧
		$I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	2.05	-	-	٧
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.9	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.72	-	-	٧
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.6	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_O = 20 \mu A$ ; $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.1	٧
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	$0.3 \times V_{CC}$	V
		$I_O = 1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	-	-	0.31	V
		$I_O = 1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	-	-	0.31	٧
		$I_O = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.31	٧
		$I_O = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.44	٧
		$I_{O} = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.31	V
		$I_{O}$ = 4.0 mA; $V_{CC}$ = 3.0 V	-	-	0.44	V
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## Low-power 2-input EXCLUSIVE-OR gate

**Table 7. Static characteristics** ...continued
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
l <sub>l</sub>	input leakage current	$V_I$ = GND to 3.6 V; $V_{CC}$ = 0 V to 3.6 V	-	-	±0.1	μΑ
OFF	power-off leakage current	$V_I$ or $V_O = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.2	μΑ
$\Delta I_{OFF}$	additional power-off leakage current	$V_1$ or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.2	μΑ
CC	supply current	$V_I$ = GND or $V_{CC}$ ; $I_O$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.5	μΑ
Δl <sub>CC</sub>	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A};$ $V_{CC} = 3.3 \text{ V}$	[1] -	-	40	μΑ
Cı	input capacitance	$V_{CC}$ = 0 V to 3.6 V; $V_I$ = GND or $V_{CC}$	-	0.8	-	pF
Co	output capacitance	$V_O = GND; V_{CC} = 0 V$	-	1.7	-	рF
T <sub>amb</sub> = -	40 °C to +85 °C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 0.8 V	$0.70 \times V_{CC}$	-	-	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	$0.65 \times V_{CC}$	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 0.8 V	-	-	$0.30 \times V_{CC}$	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	$0.35 \times V_{CC}$	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	٧
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_{O} = -20 \mu A$ ; $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	V <sub>CC</sub> - 0.1	-	-	V
		$I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.7 \times V_{CC}$	-	-	V
		$I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	1.03	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.30	-	-	٧
		$I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.97	-	-	٧
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.85	-	-	٧
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.67	-	-	٧
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.55	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_O = 20 \mu A$ ; $V_{CC} = 0.8 \text{ V}$ to 3.6 V	-	-	0.1	V
		$I_O = 1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	-	-	$0.3 \times V_{CC}$	V
		$I_O = 1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	-	-	0.37	٧
		$I_O = 1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	-	-	0.35	V
		$I_{O} = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.33	٧
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.45	٧
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.33	٧
		$I_O = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.45	V
   <sub> </sub>	input leakage current	$V_{I} = GND \text{ to } 3.6 \text{ V}; V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.5	μΑ
OFF	power-off leakage current	$V_1$ or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.5	μΑ
$\Delta I_{OFF}$	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.6	μΑ

## Low-power 2-input EXCLUSIVE-OR gate

**Table 7. Static characteristics** ...continued
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Uni
Icc	supply current	$V_I$ = GND or $V_{CC}$ ; $I_O$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.9	μΑ
∆l <sub>CC</sub>	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A};$ $V_{CC} = 3.3 \text{ V}$	<u>[1]</u> -	-	50	μΑ
T <sub>amb</sub> = -	40 °C to +125 °C					
V <sub>IH</sub>	HIGH-level input voltage	$V_{CC} = 0.8 \text{ V}$	$0.75 \times V_{CC}$	-	-	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	$0.70 \times V_{CC}$	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		$V_{CC}$ = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 0.8 V	-	-	$0.25 \times V_{CC}$	٧
		V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	$0.30 \times V_{CC}$	٧
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	-	0.7	V
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	-	-	0.9	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_{O} = -20 \mu A$ ; $V_{CC} = 0.8 \text{ V}$ to 3.6 V	V <sub>CC</sub> - 0.11	-	-	V
		$I_O = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.6 \times V_{CC}$	-	-	V
		$I_O = -1.7 \text{ mA}$ ; $V_{CC} = 1.4 \text{ V}$	0.93	-	-	V
		$I_O = -1.9 \text{ mA}$ ; $V_{CC} = 1.65 \text{ V}$	1.17	-	-	V
		$I_O = -2.3 \text{ mA}$ ; $V_{CC} = 2.3 \text{ V}$	1.77	-	-	V
		$I_O = -3.1 \text{ mA}$ ; $V_{CC} = 2.3 \text{ V}$	1.67	-	-	V
		$I_O = -2.7 \text{ mA}$ ; $V_{CC} = 3.0 \text{ V}$	2.40	-	-	V
		$I_O = -4.0 \text{ mA}$ ; $V_{CC} = 3.0 \text{ V}$	2.30	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_O = 20 \mu A$ ; $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.11	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.33 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.41	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.39	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.36	V
		$I_{O} = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.50	V
		$I_{O} = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.36	V
		$I_{O} = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.50	V
ı	input leakage current	$V_{I} = GND \text{ to } 3.6 \text{ V}; V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.75	μΑ
OFF	power-off leakage current	$V_1$ or $V_0 = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V}$	-	-	±0.75	μA
∆l <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.75	μA
СС	supply current	V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	1.4	μΑ
Δl <sub>CC</sub>	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A};$ $V_{CC} = 3.3 \text{ V}$	[1] -	-	75	μΑ

<sup>[1]</sup> One input at  $V_{CC}$  – 0.6 V, other input at  $V_{CC}$  or GND.

## Low-power 2-input EXCLUSIVE-OR gate

## 11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 9

Symbol	Parameter	Conditions		Min	Typ[1]	Max	Unit
T <sub>amb</sub> = 25	°C; C <sub>L</sub> = 5 pF						
t <sub>pd</sub>	propagation delay	A or B to Y; see Figure 8	[2]				
		$V_{CC} = 0.8 \text{ V}$		-	21.2	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V		2.3	5.9	13.1	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$		1.8	4.1	7.7	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V		1.5	3.3	5.9	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.2	2.6	4.4	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.0	2.3	4.0	ns
T <sub>amb</sub> = 25	°C; C <sub>L</sub> = 10 pF						
t <sub>pd</sub>	propagation delay	A or B to Y; see Figure 8	[2]				
		$V_{CC} = 0.8 \text{ V}$		-	24.7	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		2.6	6.8	14.8	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$		2.2	4.8	8.7	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		1.8	3.9	6.7	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.5	3.1	5.2	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.3	2.9	4.8	ns
T <sub>amb</sub> = 25	°C; C <sub>L</sub> = 15 pF						
t <sub>pd</sub>	propagation delay	A or B to Y; see Figure 8	[2]				
		V <sub>CC</sub> = 0.8 V		-	28.2	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V		3.0	7.6	16.5	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$		2.4	5.3	9.6	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V		2.1	4.4	7.5	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.8	3.6	5.9	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.6	3.3	5.4	ns
T <sub>amb</sub> = 25	°C; C <sub>L</sub> = 30 pF						
t <sub>pd</sub>	propagation delay	A or B to Y; see Figure 8	[2]				
		V <sub>CC</sub> = 0.8 V		-	38.5	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		3.9	9.9	21.5	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$		3.2	6.9	12.5	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		2.8	5.7	9.8	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		2.4	4.7	7.6	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		2.2	4.4	7.1	ns

#### Low-power 2-input EXCLUSIVE-OR gate

 Table 8.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 9

Symbol	Parameter	Conditions		Min	Typ[1]	Max	Unit
$T_{amb} = 25$	°C						
$C_{PD}$	power dissipation capacitance	$f = 1 \text{ MHz}$ ; $V_I = \text{GND to } V_{CC}$	[3]				
		$V_{CC} = 0.8 \text{ V}$		-	2.7	-	pF
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		-	2.9	-	pF
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$		-	3.0	-	pF
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		-	3.1	-	pF
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		-	3.6	-	pF
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		-	4.2	-	pF

<sup>[1]</sup> All typical values are measured at nominal  $V_{CC}$ .

 $P_D = C_{PD} \times V_{CC}{}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}{}^2 \times f_o) \text{ where:}$ 

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

 $V_{CC}$  = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 9

Symbol	Parameter	Parameter Conditions		–40 °C t	o +85 °C	-40 °C to	+125 °C	Unit
				Min	Max	Min	Max	
$C_L = 5 pF$								
t <sub>pd</sub>	propagation delay	A or B to Y; see Figure 8	[1]					
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		2.1	14.3	2.1	15.8	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$		1.6	8.8	1.6	9.7	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		1.4	6.9	1.4	7.6	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.1	5.3	1.1	5.9	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		0.9	4.7	0.9	5.2	ns
C <sub>L</sub> = 10 pF								
t <sub>pd</sub>	propagation delay	A or B to Y; see Figure 8	[1]					
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		2.4	16.2	2.4	17.9	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$		1.9	10.0	1.9	11.0	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		1.7	8.0	1.7	8.8	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.4	6.2	1.4	6.9	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.3	5.6	1.3	6.2	ns

<sup>[2]</sup>  $t_{pd}$  is the same as  $t_{PZL}$  and  $t_{PLZ}$ .

<sup>[3]</sup>  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

#### Low-power 2-input EXCLUSIVE-OR gate

 Table 9.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 9

Symbol	Parameter	Conditions		–40 °C t	o +85 °C	-40 °C to	Unit	
				Min	Max	Min	Max	
$C_L = 15 pF$			'		'			'
t <sub>pd</sub>	propagation delay	A or B to Y; see Figure 8	<u>[1]</u>					
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		2.7	18.1	2.7	20.0	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$		2.2	11.3	2.2	12.5	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		1.9	9.0	1.9	9.9	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.6	7.0	1.6	7.7	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.5	6.4	1.5	7.1	ns
$C_L = 30 pF$	-							
t <sub>pd</sub>	propagation delay	A or B to Y; see Figure 8	<u>[1]</u>					
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		3.5	24.1	3.5	26.6	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$		2.8	14.8	2.8	16.3	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		2.5	11.7	2.5	12.9	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		2.2	9.1	2.2	10.1	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		2.1	8.3	2.1	9.2	ns

<sup>[1]</sup>  $t_{pd}$  is the same as  $t_{PZL}$  and  $t_{PLZ}$ .

## 12. Waveforms

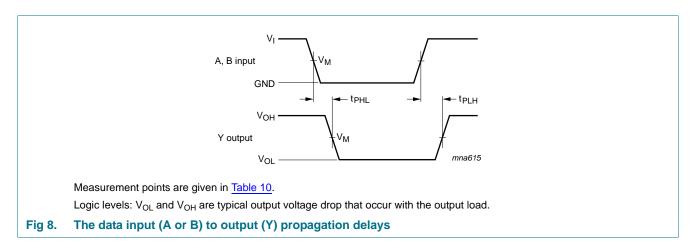
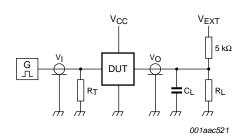


Table 10. Measurement points

Supply voltage	Output	Input		
V <sub>CC</sub>	V <sub>M</sub>	V <sub>M</sub>	VI	$t_r = t_f$
0.8 V to 3.6 V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	V <sub>CC</sub>	≤ 3.0 ns

#### Low-power 2-input EXCLUSIVE-OR gate



Test data is given in Table 11.

Definitions for test circuit:

R<sub>L</sub> = Load resistance.

C<sub>L</sub> = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to the output impedance  $Z_0$  of the pulse generator.

 $V_{EXT}$  = External voltage for measuring switching times.

Fig 9. Test circuit for measuring switching times

#### Table 11. Test data

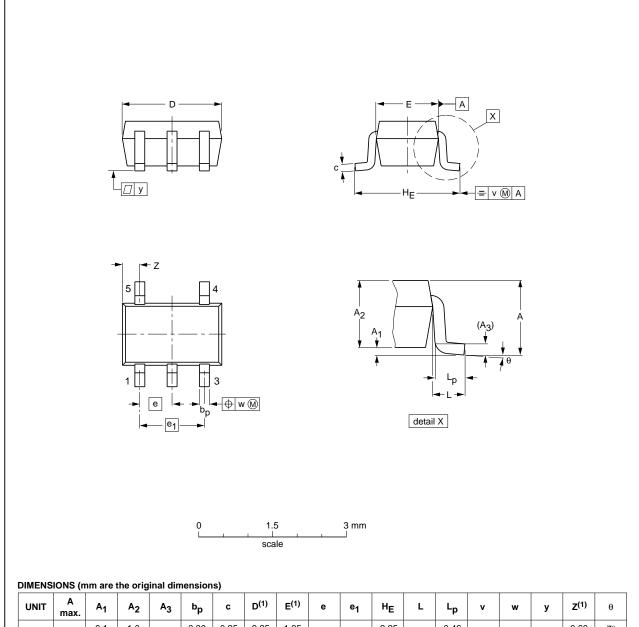
Supply voltage	Load		V <sub>EXT</sub>				
V <sub>CC</sub>	C <sub>L</sub>	R <sub>L</sub> [1]	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>		
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 k $\Omega$ or 1 M $\Omega$	open	GND	$2\times V_{CC}$		

[1] For measuring enable and disable times  $R_L$  = 5  $k\Omega$ , for measuring propagation delays, setup and hold times and pulse width  $R_L$  = 1  $M\Omega$ .

## 13. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	e <sub>1</sub>	HE	L	Lp	v	w	у	Z <sup>(1)</sup>	θ
mm	1.1	0.1 0	1.0 0.8	0.15	0.30 0.15	0.25 0.08	2.25 1.85	1.35 1.15	0.65	1.3	2.25 2.0	0.425	0.46 0.21	0.3	0.1	0.1	0.60 0.15	7° 0°

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	1330E DATE
SOT353-		MO-203	SC-88A			<del>-00-09-01</del> 03-02-19

Fig 10. Package outline SOT353-1 (TSSOP5)

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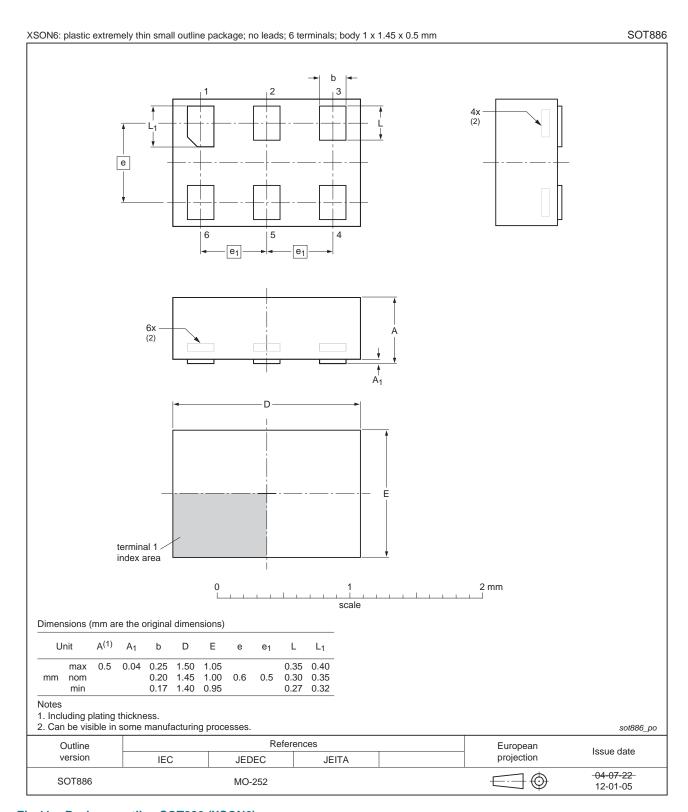


Fig 11. Package outline SOT886 (XSON6)

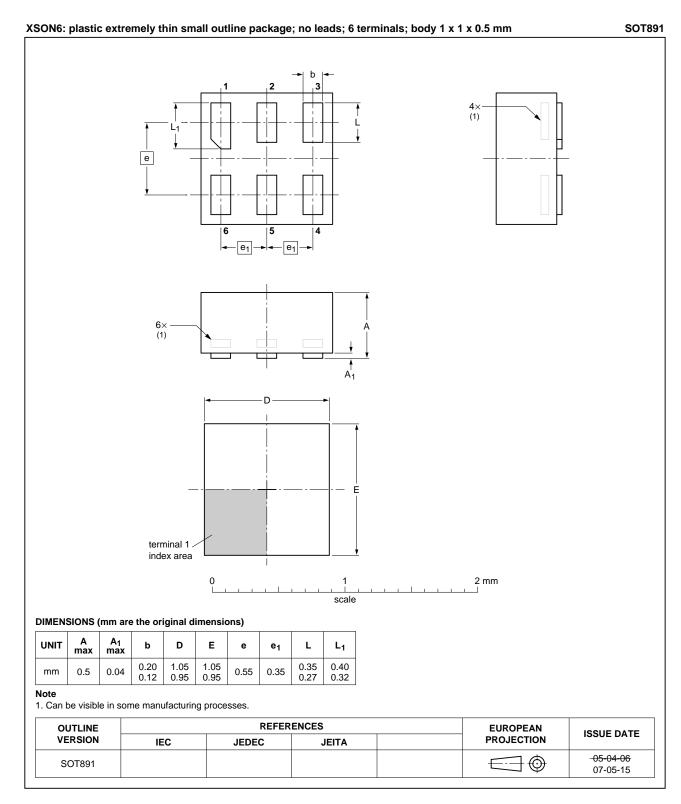


Fig 12. Package outline SOT891 (XSON6)

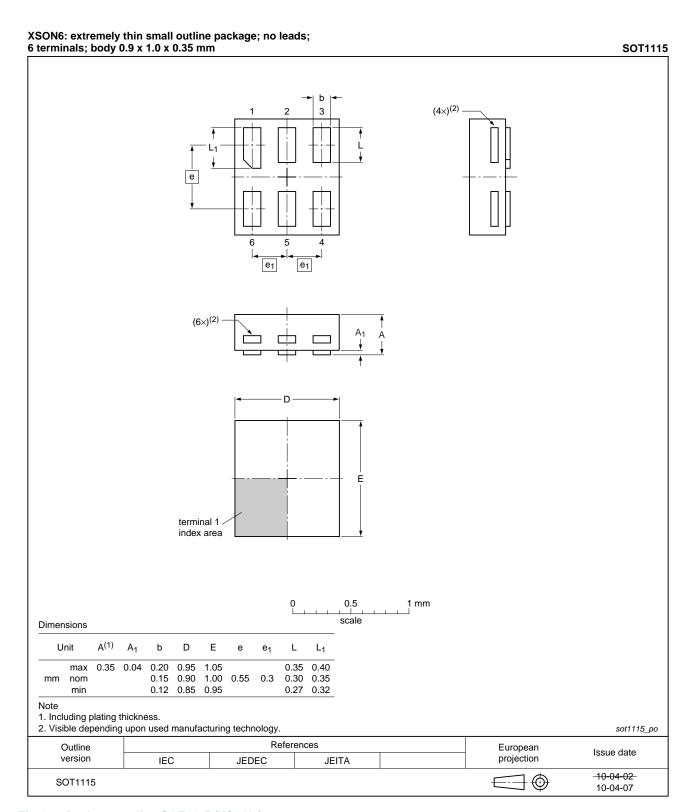


Fig 13. Package outline SOT1115 (XSON6)

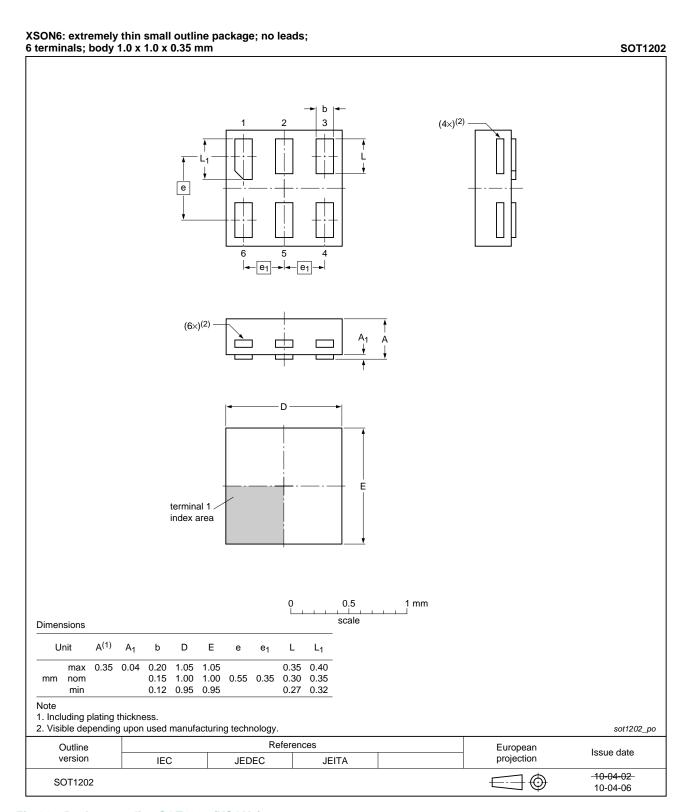


Fig 14. Package outline SOT1202 (XSON6)

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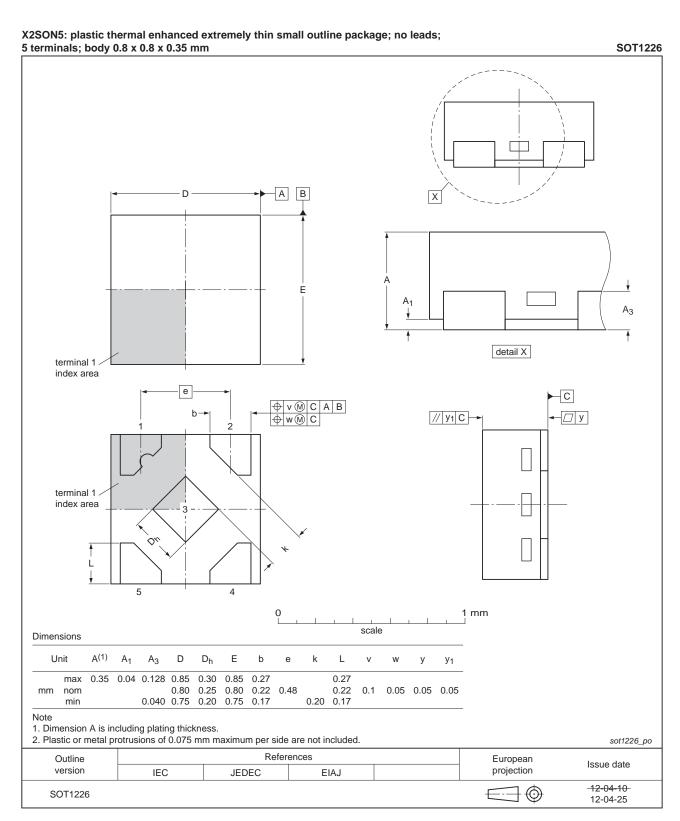


Fig 15. Package outline SOT1226 (X2SON5)

**Product data sheet** 

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## Low-power 2-input EXCLUSIVE-OR gate

## 14. Abbreviations

#### Table 12. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

# 15. Revision history

#### Table 13. Revision history

74AUP1G86 v.5 20° Modifications:		Product data sheet	-	74AUP1G86 v.4
Modifications:	Added type burne			14AUF 1000 V.4
Modifications.	Added type numb	oer 74AUP1G86GX (SOT1226)		
•	<ul> <li>Package outline of</li> </ul>	drawing of SOT886 (Figure 11)	modified.	
74AUP1G86 v.4 201	)111129 I	Product data sheet	-	74AUP1G86 v.3
Modifications:	Legal pages upda	ated.		
74AUP1G86 v.3 201	101005 I	Product data sheet	-	74AUP1G86 v.2
74AUP1G86 v.2 200	060628 I	Product data sheet	-	74AUP1G86 v.1
74AUP1G86 v.1 200	050805 I	Product data sheet	-	-

#### Low-power 2-input EXCLUSIVE-OR gate

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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## Low-power 2-input EXCLUSIVE-OR gate

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